NSN 5961-00-110-7417

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Inclosure Material:

Metal

Overall Length:

Between 1.062 inches and 1.330 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.662 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

7.50 amperes source cutoff current and 7.50 amperes source cutoff current blank

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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